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DDP 8Gb D-die DDR3L SDRAM - Texas Instruments

The DDP 8Gb DDR3 SDRAM B-die is organized as a 64Mbit x 16 I/Os x 8banks device. This synchronous device achieves high speed double-data-rate transfer rates of up to 1600Mb/sec/pin (DDR3-1600) for general applications. The chip is designed to comply with the following key DDR3 SDRAM features-

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Transitioning DDR3 8Gb DDP 2CS to 8Gb SDP 1CS Introduction This technical note explains how to transition a dual-rank 8Gb 2CS (dual die) MT41K512M16 DDP device to a single-rank 8Gb 1CS (monolithic) MT41K512M16 SDP device without changing density, bandwidth, ball assignments, or trace routing in the PCB design.

TN-41-16: DDR3L MT41K512M16 DDP to SDP Transition Guide

Page 5 of 59Rev. 1.0 March 2009DDP 4Gb DDR3 SDRAMK4B4G0446BK4B4G0846B1.0 Ordering Information[Table 1] Samsung DDP 4Gb DDR3 B-die ordering information tableNote :1. Speed bin is in order of CL-tRCD-tRP.2.0 Key Features datasheet search, datasheets, Datasheet search site for Electronic Components and Semiconductors, integrated circuits, diodes and other semiconductors.

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Page 4 of 59Rev. 1.0 March 2009DDP 4Gb DDR3 SDRAMK4B4G0446BK4B4G0846B9.9 ODT Timing Definitions..... 259.9.1 Test Load for ODT Timings..... 259.9.2 ODT Timing Definition datasheet search, datasheets, Datasheet search site for Electronic Components and Semiconductors, integrated circuits, diodes and other semiconductors.

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Transitioning Designs from DDR3 8Gb SDP 1CS to 8Gb DDP 1CS Introduction. This technical note explains how to migrate a PCB design that uses a Micron 8Gb DDR3L product from a 90 series single-die 96-ball package to a 100 series dual-die 96-ball package. For complete specifications, see the data sheet for each device.

TN-41-17: DDR3L MT41K512M16 SDP to DDP Migration Guide

DDP 4Gb DDR3 SDRAM K4B4G0446B K4B4G0846B DDP 4Gb B-die DDR3 SDRAM Specification 78 FBGA with Lead-Free & Halogen-Free (RoHS Compliant) * Samsung Electronics reserves the right to change products or specification without notice. INFORMATION IN THIS DOCUMENT IS PROVIDED IN RELATION TO SAMSUNG PRODUCTS, AND IS SUBJECT TO CHANGE WITHOUT NOTICE.

DDP 4Gb B-die DDR3 SDRAM Specification - Nexthardware

DDP packages include two DRAM dies in a memory package and are used when you need to increase memory density, but don't have the memory module real estate to accommodate all those monolithic memory packages. Each DDP memory package includes two DRAM dies - 4Gbit DRAM die x 2 - in one memory package.

DDP vs. monolithic memory packages and their impact ...

• Programmable CAS Write Latency(CWL) = 5(DDR3-800), 6(DDR3-1066), 7(DDR3-1333), 8(DDR3-1600) and 9(DDR3-1866) • Burst Length: 8 (Interleave without any limit, sequential with starting address "000" only), 4 with tCCD = 4 which does not allow seamless read or write [either On the fly using A12 or MRS]

240pin Registered DIMM based on 4Gb B-die

Find Samsung B-Die DDR 4 memory kits on Amazon, Newegg and many more. Search. Database updated mid-march 2020. Explanation of speed and timings on reddit.Full list of verified B-Die kits at hardwareluxx.de.

B-Die Finder - GitHub Pages

Speed bin is in order of , Rev. 1.0, Feb. 2013 K4B8G1646B DDP 8Gb B-die DDR3 SDRAM 96FBGA with Lead-Free & Halogen-Free , K4B8G1646B Rev. 1.0 Industrial DDP DDR3 SDRAM Revision History Revision No. 1.0 History Draft Date -2- Editor Feb. 2013 - First SPEC.

K4B8G datasheet & applicatoin notes - Datasheet Archive

4G x72 32GB M393A4K40BB2 CTD B (2Rx4) 2G x4 * 36pcs 8Gb B-die 16 2 78ball FBGA 31.25mm MP 8G x72 64GB M393A8K40B21 CRB A (4Rx4) 3DS 2H 8G x4 * 36pcs

DDR4 Product guide May.18 - Samsung Electronics America

Product Guide DDR3SDRAMMemory Feb. 2011 2. DDR3SDRAMComponent Product Guide ... DDP 8G B-die 8Banks K4B8G0446B MCF8/F9/K0/MA 1G x 4 1.5V 78 ball FBGA 3Q'11 ... M391B1G73BH0 CF8/H9/K0/MA 512M x 8 * 18 pcs 4Gb B-die 2Q'11 240Pin DDR3 Unbuffered DIMM Org. Density Part Number Speed Raw Card Composition Comp. Version Internal

ddr3 product guide Samsung - compuram.biz

DDP 8G B-die. 8Banks K4B8G0446B MCF8/F9/K0/MA 1G x 4 1.5V 78 ball FBGA ... DDR3 SDRAM Memory. Feb. 2011. 4. DDR3 SDRAM Module Product Guide. ... M378B1G73BH0 CF8/H9/K0/MA 512M x 8 * 16 pcs 4Gb B-die 2Q'11 1Gx 72 8GB M391B1G73AH0 CF8/H9/K0 E(2Rx8) 512M x 8 * 18 pcs 4Gb A-die 82 78 ball FBGA

DDR3 SDRAM Memory Product Guide - BDTIC

Based 512Mx4 (4GB/8GB) SDRAM B-Die Based DDR3-1066 1Gx4 (DDP) (1.6GB) SDRAM B-Die Features

NT8GC72B4NB1NK-CG datasheet - Specifications: Memory ...

240pin DDR3 SDRAM Registered DIMM *SK hynix reserves the right to change products or specifications without notice. DDR3 SDRAM Registered DIMM Based on 4Gb B-die HMT451R7BFR8C HMT41GR7BFR8C HMT41GR7BFR4C HMT42GR7BFR4C HMT84GR7BMR4C

DDR3 SDRAM Registered DIMM Based on 4Gb B-die

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